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BP 2095

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Examiner Initials *	Cite No.1	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code 2 (if known)			
	1	5,886,589		Mourant	03/23/99	
	2	6,133,806		Sheen	10/17/00	
	3	5,877,667		Wollesen	3/2/99	
	4	6,188,306		Wollesen	2/13/01	

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				Application Number	
				Filing Date	
				First Named Inventor	Yang
				Group Art Unit	
Sheet	2	of	2	Examiner Name	
				Attorney Docket Number	BP 2095

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	1	DANESH, "A Q-Factor enhancement technique for MMIC inductors", IEEE MTT-S Digest, pp. 183-186, June 1998	<input type="checkbox"/>
	2	ZHOU, "Monolithic transformers and their application in a differential CMOS RF low-noise amplifier", IEEE Journal of Solid State Circuits, vol. 33, pp. 2020-2027, Dec. 98	<input type="checkbox"/>
	3	LONG, "Monolithic transformers for silicon RF IC design", IEEE Journal of Solid-State Circuits, vol. 35, pp. 1368-1381, Sept. 2000	<input type="checkbox"/>
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